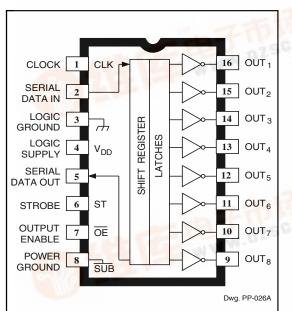
查询UCN5821供应商

捷多邦,专业PCB打样工厂,24小时加急出货

5821 AND 5822



Note the DIP package and the SOIC package are electrically identical and share common terminal number assignments.

ABSOLUTE MAXIMUM RATINGS at 25°C Free-Air Temperature

Output Voltage, V _{OUT}
UCN5821A & UCN5821LW 50 V UCN5822A & UCN5822LW 80 V
Logic Supply Voltage, V _{DD} 15 V
Input Voltage Range,
V_{IN}
Continuous Output Current,
Ι _{ΟUT} 500 mA
Package Power Dissipation, P _D Package Code 'A' 2.1 W Package Code 'LW' 1.5 W
Operating Temperature Range,
T _A 20°C to +85°C
Storage Temperature Range, T _S 55°C to +150°C
Caution: CMOS devices have input static protection but are susceptible to damage when exposed to

extremely high static electrical charges.

PDF

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BiMOS II 8-BIT SERIAL-INPUT, LATCHED DRIVERS

A merged combination of bipolar and MOS technology gives these devices an interface flexibility beyond the reach of standard logic buffers and power driver arrays. The UCN5821A, UCN5821LW, UCN5822A, and UCN5822LW each have an eight-bit CMOS shift register and CMOS control circuitry, eight CMOS data latches, and eight bipolar current-sinking Darlington output drivers. The UCN5821A/LW and UCN5822A/LW are identical except for rated output voltage.

BiMOS II devices have much higher data-input rates than the original BiMOS circuits. With a 5 V logic supply, they will typically operate at better than 5 MHz. With a 12 V supply, significantly higher speeds are obtained. The CMOS inputs are compatible with standard CMOS and NMOS logic levels. TTL circuits may require the use of appropriate pull-up resistors. By using the serial data output, the drivers can be cascaded for interface applications requiring additional drive lines.

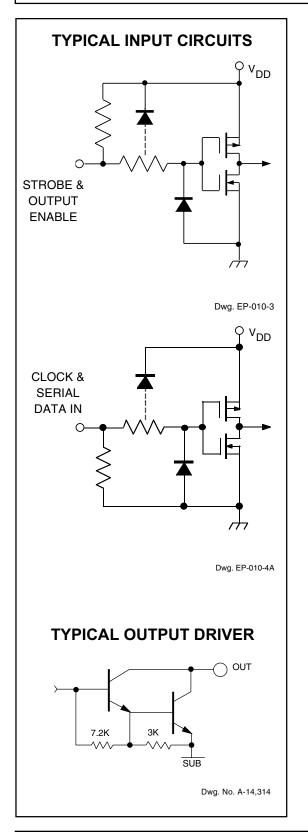
The UCN5821/22A are furnished in a standard 16-pin plastic DIP; the UCN5821/22LW are in a 16-lead wide-body SOIC for surface-mount applications. The UCN5821A is also available for operation from -40°C to +85°C. To order, change the prefix from 'UCN' to 'UCQ'.

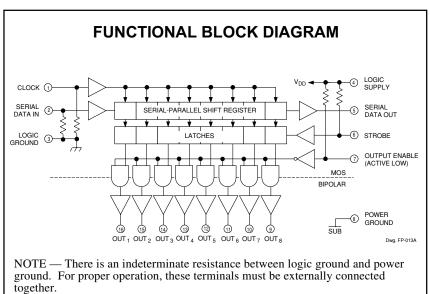
FEATURES

- To 3.3 MHz Data Input Rate
- CMOS, NMOS, TTL Compatible
- Internal Pull-Down Resistors
- Low-Power CMOS Logic & Latches
 - High-Voltage Current-Sink Outputs
 - Automotive Capable

Always order by complete part number, e.g., UCN5821A.







Number of Outputs ON (I _{OUT} = 200 mA	UCN5821A Max. Allowable Duty Cycle at Ambient Temperature of							
V _{DD} = 12 V)	25°C	40°C	50°C	60°C	70°C			
8	90%	79%	72%	65%	57%			
7	100%	90%	82%	74%	65%			
6	100%	100%	96%	86%	76%			
5	100%	100%	100%	100%	91%			
4	100%	100%	100%	100%	100%			
3	100%	100%	100%	100%	100%			
2	100%	100%	100%	100%	100%			
1	100%	100%	100%	100%	100%			

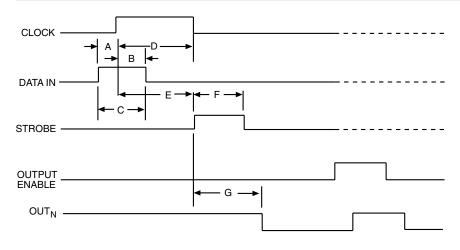
Number of Outputs ON (I _{OUT} = 200 mA	N UCN5821LW Max. Allowable Duty (at Ambient Temperature of								
V _{DD} = 12 V)	25°C	40°C	50°C	60°C	70°C				
8	67%	59%	54%	49%	43%				
7	77%	68%	62%	56%	49%				
6	90%	79%	72%	65%	57%				
5	100%	95%	86%	78%	68%				
4	100%	100%	100%	98%	86%				
3	100%	100%	100%	100%	100%				
2	100%	100%	100%	100%	100%				
1	100%	100%	100%	100%	100%				



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ELECTRICAL CHARACTERISTICS at $T_A = +25^{\circ}C$, $V_{DD} = 5$ V, (unless otherwise specified).

				Limits	
Characteristic	Symbol	Test Conditions	Min.	Max.	Units
Output Leakage	I _{CEX}	UCN5821A/LW, $V_{OUT} = 50 V$	-	50	μA
Current		UCN5822A/LW, V _{OUT} = 80 V	_	50	μA
		UCN5821A/LW, V _{OUT} = 50 V, T _A = +70°C	_	100	μA
		UCN5822A/LW, V _{OUT} = 80 V, T _A = +70°C	_	100	μA
Collector-Emitter	V _{CE(SAT)}	I _{OUT} = 100 mA	-	1.1	V
Saturation Voltage		I _{OUT} = 200 mA	—	1.3	V
		I _{OUT} = 350 mA, V _{DD} = 7.0 V	_	1.6	V
Input Voltage	V _{IN(0)}		-	0.8	V
	V _{IN(1)}	V _{DD} = 12 V	10.5		V
		V _{DD} = 5.0 V	3.5		V
Input Resistance	r _{IN}	V _{DD} = 12 V	50	_	kΩ
		V _{DD} = 5.0 V	50		kΩ
Supply Current	I _{DD(ON)}	One Driver ON, V _{DD} = 12 V	-	4.5	mA
		One Driver ON, V _{DD} = 10 V	_	3.9	mA
		One Driver ON, V _{DD} = 5.0 V	_	2.4	mA
	I _{DD(OFF)}	V _{DD} = 5.0 V, All Drivers OFF, All Inputs = 0 V	_	1.6	mA
		V _{DD} = 12 V, All Drivers OFF, All Inputs = 0 V	_	2.9	mA



Dwg. No. A-12,627

TIMING CONDITIONS (V_{DD} = 5.0 V, T_A = +25°C, Logic Levels are V_{DD} and Ground)

Α.	Minimum Data Active Time Before Clock Pulse (Data Set-Up Time)	75 ns
В.	Minimum Data Active Time After Clock Pulse (Data Hold Time)	75 ns
C.	Minimum Data Pulse Width	150 ns
D.	Minimum Clock Pulse Width	150 ns
Ε.	Minimum Time Between Clock Activation and Strobe	30 ns
F.	Minimum Strobe Pulse Width	100 ns
G.	Typical Time Between Strobe Activation and Output Transition	1.0 μs

Serial Data present at the input is transferred to the shift register on the logic "0" to logic "1" transition of the CLOCK input pulse. On succeeding CLOCK pulses, the registers shift data information towards the SERIAL DATA OUTPUT. The SERIAL DATA must appear at the input prior to the rising edge of the CLOCK input waveform.

Information present at any register is transferred to its respective latch when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Applications where the latches are bypassed (STROBE tied high) will require that the ENABLE input be high during serial data entry.

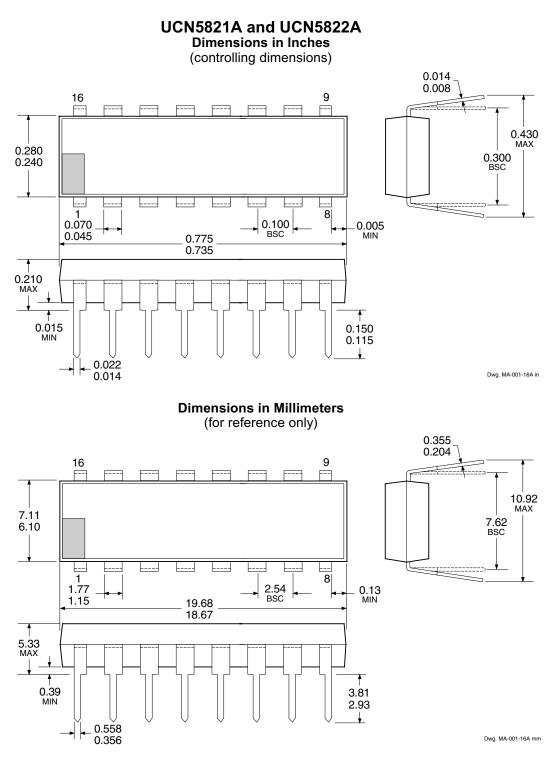
When the ENABLE input is high, all of the output buffers are disabled (OFF) without affecting the information stored in the latches or shift register. With the ENABLE input low, the outputs are controlled by the state of the latches.

Serial		Shift Register Contents Serial Latch Contents						Output Contents										
	Clock Input		I ₂	l ₃		. I ₈	- Data Output	Strobe Input	I ₁	l ₂	I ₃	I ₈	Output Enable	I ₁	I ₂	I ₃		I ₈
н	Г	Н	R ₁	R ₂		. R ₇	R ₇											
L	Г	L	R_1	R_2		. R ₇	R ₇											
Х	L	R ₁	R_2	R_3		. R ₈	R ₈											
		Х	Х	Х		. Х	Х	L	R ₁	R_2	R_3	R ₈						
		P ₁	P_2	P ₃		. P ₈	P ₈	Н	P ₁	P_2	P ₃	P ₈	L	P ₁	P2	P ₃		P ₈
									Х	Х	Х	X	Н	Н	Н	Η		Н

TRUTH TABLE

L = Low Logic Level H = High Logic Level X = Irrelevant P = Present State R = Previous State

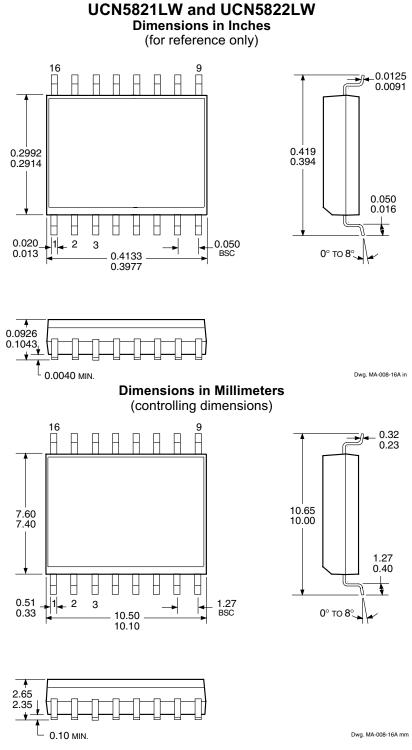




NOTES: 1. Lead thickness is measured at seating plane or below.

2. Lead spacing tolerance is non-cumulative.

3. Exact body and lead configuration at vendor's option within limits shown.



- NOTES: 1. Lead spacing tolerance is non-cumulative.
 - 2. Exact body and lead configuration at vendor's option within limits shown.

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POWER INTERFACE DRIVERS

Function	ction Output Ratings*								
SERIAL-INPUT LATCHED DRIVERS									
8-Bit (saturated drivers)	-120 mA	50 V‡	5895						
8-Bit	350 mA	50 V	5821						
8-Bit	350 mA	80 V	5822						
8-Bit	350 mA	50 V‡	5841						
8-Bit	350 mA	80 V‡	5842						
8-Bit (constant-current LED driver)	75 mA	17 V	6275						
8-Bit (DMOS drivers)	250 mA	50 V	6595						
8-Bit (DMOS drivers)	350 mA	50 V‡	6A595						
8-Bit (DMOS drivers)	100 mA	50 V	6B595						
10-Bit (active pull-downs)	-25 mA	60 V	5810-F and 6809/10						
12-Bit (active pull-downs)	-25 mA	60 V	5811 and 6811						
16-Bit (constant-current LED driver)	75 mA	17 V	6276						
20-Bit (active pull-downs)	-25 mA	60 V	5812-F and 6812						
32-Bit (active pull-downs)	-25 mA	60 V	5818-F and 6818						
32-Bit	100 mA	30 V	5833						
32-Bit (saturated drivers)	100 mA	40 V	5832						
PARALLEL	-INPUT LATCHED	DRIVERS							
4-Bit	350 mA	50 V‡	5800						
8-Bit	-25 mA	60 V	5815						
8-Bit	350 mA	50 V‡	5801						
8-Bit (DMOS drivers)	100 mA	50 V	6B273						
8-Bit (DMOS drivers)	250 mA	50 V	6273						
SPECIAL-PURPOSE DEVICES									
Unipolar Stepper Motor Translator/Driver	1.25 A	50 V‡	5804						
Addressable 8-Bit Decoder/DMOS Driver	50 V	6259							
Addressable 8-Bit Decoder/DMOS Driver	Addressable 8-Bit Decoder/DMOS Driver350 mA50 V‡6A								
Addressable 8-Bit Decoder/DMOS Driver	100 mA	50 V	6B259						
Addressable 28-Line Decoder/Driver	450 mA	30 V	6817						

* Current is maximum specified test condition, voltage is maximum rating. See specification for sustaining voltage limits. Negative current is defined as coming out of (sourcing) the output.

† Complete part number includes additional characters to indicate operating temperature range and package style.

‡ Internal transient-suppression diodes included for inductive-load protection.

